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August 2003

**Monolithic Quad SPST CMOS Analog Switches**

**Features**

- This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- ON-Resistance <35Ω Max
- Low Power Consumption (P<sub>D</sub> <35μW)
- Fast Switching Action
  - t<sub>ON</sub> <175ns
  - t<sub>OFF</sub> <145ns
- Low Charge Injection
- Upgrade from DG211/DG212
- TTL, CMOS Compatible
- Single or Split Supply Operation

**Applications**

- Audio Switching
- Battery Operated Systems
- Data Acquisition
- Hi-Rel Systems
- Sample and Hold Circuits
- Communication Systems
- Automatic Test Equipment

**Description**

The DG411/883 series monolithic CMOS analog switches are drop-in replacements for the popular DG211 and DG212 series devices. They include four independent single pole throw (SPST) analog switches, and TTL and CMOS compatible digital inputs.

These switches feature lower analog ON resistance (<35Ω) and faster switch time (t<sub>ON</sub> <175ns) compared to the DG211 or DG212. Charge injection has been reduced, simplifying sample and hold applications.

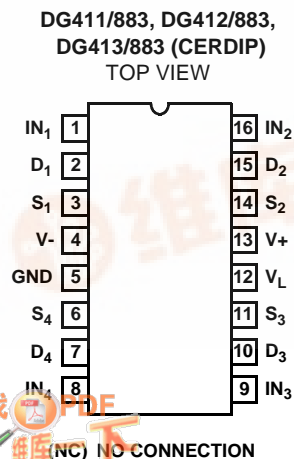
The improvements in the DG411/883 series are made possible by using a high voltage silicon-gate process. An epitaxial layer prevents the latch-up associated with older CMOS technologies. The 44V maximum voltage range permits controlling 40V<sub>P-P</sub> signals. Power supplies may be single-ended from +5V to +34V, or split from ±5V to ±20V.

The four switches are bilateral, equally matched for AC or bidirectional signals. The ON resistance variation with analog signals is quite low over a ±15V analog input range. The switches in the DG411/883 and DG412/883 are identical, differing only in the polarity of the selection logic. Two of the switches in the DG413/883 (#1 and #4) use the logic of the DG211 and DG411/883 (i.e. a logic "0" turns the switch ON) and the other two switches use DG212 and DG412/883 positive logic. This permits independent control of turn-on and turn-off times for SPDT configurations, permitting "break-before-make" or "make-before-break" operation with a minimum of external logic.

**Part Number Information**

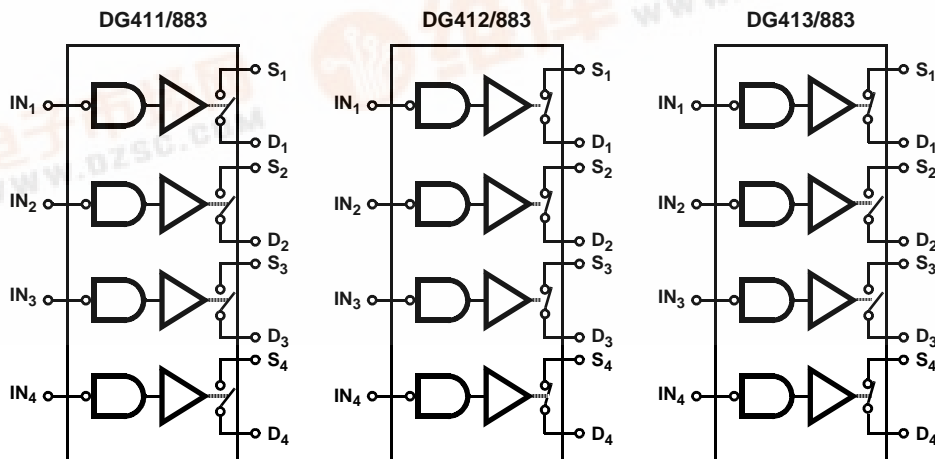
| PART NUMBER | TEMP. RANGE     | PACKAGE        |
|-------------|-----------------|----------------|
| DG411AK/883 | -55°C to +125°C | 16 Lead CerDIP |
| DG412AK/883 | -55°C to +125°C | 16 Lead CerDIP |
| DG413AK/883 | -55°C to +125°C | 16 Lead CerDIP |

**Pinout**



**Functional Diagrams**

Four SPST Switches per Package Switches Shown for Logic "1" Input



**DG411/883, DG412/883, DG413/883**

**Pin Description**

| PIN | SYMBOL          | DESCRIPTION                                |
|-----|-----------------|--|
| 1   | IN <sub>1</sub> | Logic Control for Switch 1                 |
| 2   | D <sub>1</sub>  | Drain (Output) Terminal for Switch 1       |
| 3   | S <sub>1</sub>  | Source (Input) Terminal for Switch 1       |
| 4   | V-              | Negative Power Supply Terminal             |
| 5   | GND             | Ground Terminal (Logic Common)             |
| 6   | S <sub>4</sub>  | Source (Input) Terminal for Switch 4       |
| 7   | D <sub>4</sub>  | Drain (Output) Terminal for Switch 4       |
| 8   | IN <sub>4</sub> | Logic Control for Switch 4                 |
| 9   | IN <sub>3</sub> | Logic Control for Switch 3                 |
| 10  | D <sub>3</sub>  | Drain (Output) Terminal for Switch 3       |
| 11  | S <sub>3</sub>  | Source (Input) Terminal for Switch 3       |
| 12  | V <sub>L</sub>  | Logic Reference Voltage                    |
| 13  | V+              | Positive Power Supply Terminal (Substrate) |
| 14  | S <sub>2</sub>  | Source (Input) Terminal for Switch 2       |
| 15  | D <sub>2</sub>  | Drain (Output) Terminal for Switch 2       |
| 16  | IN <sub>2</sub> | Logic Control for Switch 2                 |

**TRUTH TABLE**

| LOGIC | DG411/<br>883 | DG412/<br>883 | DG413/883      |                |
|-------|---------------|---------------|----------------|----------------|
|       | SWITCH        | SWITCH        | SWITCH<br>1, 4 | SWITCH<br>2, 3 |
| 0     | ON            | OFF           | OFF            | ON             |
| 1     | OFF           | ON            | ON             | OFF            |

NOTE: Logic "0" ≤ 0.8V. Logic "1" ≥ 2.4V.

## Specifications DG411/883, DG412/883, DG413/883

### Absolute Maximum Ratings

|  |   |
|--|---|
| V+ to V-   | 44V   |
| GND to V-  | 25V   |
| V <sub>L</sub> (Note 2)                                  | (GND -0.3V) to (V+) +0.3V                               |
| Digital Inputs, V <sub>S</sub> , V <sub>D</sub> (Note 2) | (V-) -2V to (V+) +2V or 30mA,<br>Whichever Occurs First |
| Continuous Current (Any Terminal)                        | 30mA  |
| Current, S or D (Pulsed 1ms, 10% Duty Cycle)             | 100mA   |
| Storage Temperature Range (A Suffix)                     | -65°C to +125°C   |
| Lead Temperature (Soldering 10s)                         | +300°C  |

### Thermal Information

|                                  |                 |               |
|----------------------------------|-----------------|---------------|
| Thermal Resistance (Note 3)      | $\theta_{JA}$   | $\theta_{JC}$ |
| CerDIP Package                   | 75°C/W          | 20°C/W        |
| Junction Temperature             | +175°C          |               |
| Operating Temperature (A Suffix) | -55°C to +125°C |               |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

### Operating Conditions

|                             |                 |                          |          |
|-----------------------------|-----------------|--------------------------|----------|
| Operating Voltage Range     | ±20V Max        | Input High Voltage       | 2.4V Min |
| Operating Temperature Range | -55°C to +125°C | Input Rise and Fall Time | ≤20ns    |
| Input Low Voltage           | 0.8V Max        |                          |          |

**TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS**

Device Tested at: V+ = +15V, V- = -15V, V<sub>L</sub> = 5V, GND = 0V, Unless Otherwise Specified

| PARAMETERS   | SYMBOL              | CONDITIONS  |   | GROUP A<br>SUBGROUP   | TEMPERATURE                                | LIMITS       |               | UNITS |       |    |
|--|---------------------|---|---|---|--|--------------|---------------|-------|-------|----|
|  |                     |   |   |   |  | MIN          | MAX           |       |       |    |
| Drain-to-Source<br>ON Resistance<br>DG411/883<br>DG412/883<br>DG413/883<br>DG411/883<br>DG412/883<br>DG413/883 | R <sub>DS(ON)</sub> | V+ = +13.5V,<br>V- = -13.5V,<br>I <sub>S</sub> = -10mA,<br>V <sub>D</sub> = ±8.5V | V <sub>IN</sub> = 0.8V  | 1, 3  | +25°C, -55°C                               | 0            | 35            | Ω     |       |    |
|  |                     |   |   | 2   | +125°C                                     | 0            | 45            | Ω     |       |    |
|  |                     |   | V <sub>IN</sub> = 2.4V  | 1, 3  | +25°C, -55°C                               | 0            | 35            | Ω     |       |    |
|  |                     |   |   | 2   | +125°C                                     | 0            | 45            | Ω     |       |    |
|  |                     |   | V <sub>IN</sub> = 0.8V or<br>2.4V (Note 1)  | 1, 3  | +25°C, -55°C                               | 0            | 35            | Ω     |       |    |
|  |                     |   |   | 2   | +125°C                                     | 0            | 45            | Ω     |       |    |
|  |                     | DG411/883<br>DG412/883<br>DG413/883   | V+ = +10.8V,<br>V- = -0V,<br>I <sub>S</sub> = -10mA,<br>V <sub>D</sub> = 3.0V and<br>8.0V | V <sub>IN</sub> = 0.8V  | 1, 3                                       | +25°C, -55°C | 0             | 80    | Ω     |    |
|  |                     |   |   |   | 2  | +125°C       | 0             | 100   | Ω     |    |
|  |                     |   |   | V <sub>IN</sub> = 2.4V  | 1, 3                                       | +25°C, -55°C | 0             | 80    | Ω     |    |
|  |                     |   |   |   | 2  | +125°C       | 0             | 100   | Ω     |    |
|  |                     |   |   | V <sub>IN</sub> = 0.8V or<br>2.4V (Note 1)  | 1, 3                                       | +25°C, -55°C | 0             | 80    | Ω     |    |
|  |                     |   |   |   | 2  | +125°C       | 0             | 100   | Ω     |    |
| Source OFF Leakage Current<br>DG411/883<br>DG412/883<br>DG413/883<br>DG411/883<br>DG412/883<br>DG413/883       | I <sub>S(OFF)</sub> | V+ = 16.5V,<br>V- = -16.5V,<br>V <sub>D</sub> = -15.5V,<br>V <sub>S</sub> = 15.5V | V <sub>IN</sub> = 2.4V  | 1   | +25°C                                      | -0.25        | +0.25         | nA    |       |    |
|  |                     |   |   | 2, 3  | +125°C, -55°C                              | -20          | +20           | nA    |       |    |
|  |                     |   | V <sub>IN</sub> = 0.8V  | 1   | +25°C                                      | -0.25        | +0.25         | nA    |       |    |
|  |                     |   |   | 2, 3  | +125°C, -55°C                              | -20          | +20           | nA    |       |    |
|  |                     |   | V <sub>IN</sub> = 0.8V or<br>2.4V (Note 1)  | 1   | +25°C                                      | -0.25        | +0.25         | nA    |       |    |
|  |                     |   |   | 2, 3  | +125°C, -55°C                              | -20          | +20           | nA    |       |    |
|  |                     |   | DG411/883<br>DG412/883<br>DG413/883   | V+ = 16.5V,<br>V- = -16.5V,<br>V <sub>D</sub> = 15.5V,<br>V <sub>S</sub> = -15.5V | V <sub>IN</sub> = 2.4V                     | 1            | +25°C         | -0.25 | +0.25 | nA |
|  |                     |   |   |   |  | 2, 3         | +125°C, -55°C | -20   | +20   | nA |
|  |                     |   |   |   | V <sub>IN</sub> = 0.8V                     | 1            | +25°C         | -0.25 | +0.25 | nA |
|  |                     |   |   |   |  | 2, 3         | +125°C, -55°C | -20   | +20   | nA |
|  |                     |   |   |   | V <sub>IN</sub> = 0.8V or<br>2.4V (Note 1) | 1            | +25°C         | -0.25 | +0.25 | nA |
|  |                     |   |   |   |  | 2, 3         | +125°C, -55°C | -20   | +20   | nA |

## Specifications DG411/883, DG412/883, DG413/883

**TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)**

Device Tested at:  $V_+ = +15V$ ,  $V_- = -15V$ ,  $V_L = 5V$ ,  $GND = 0V$ , Unless Otherwise Specified

| PARAMETERS  | SYMBOL                  | CONDITIONS   | GROUP A<br>SUBGROUP                 | TEMPERATURE   | LIMITS        |                         | UNITS |      |    |
|---|-------------------------|--|-------------------------------------|---|---------------|-------------------------|-------|------|----|
|   |                         |  |                                     |   | MIN           | MAX                     |       |      |    |
| Drain OFF Leakage Current<br>DG411/883<br>DG412/883<br>DG413/883<br>DG411/883<br>DG412/883<br>DG413/883 | $I_{D(OFF)}$            | $V_+ = 16.5V$ ,<br>$V_- = -16.5V$ ,<br>$V_D = -15.5V$ ,<br>$V_S = 15.5V$ | $V_{IN} = 2.4V$                     | 1   | +25°C         | -0.25                   | +0.25 | nA   |    |
|   |                         |  |                                     | 2, 3  | +125°C, -55°C | -20                     | +20   | nA   |    |
|   |                         |  | $V_{IN} = 0.8V$                     | 1   | +25°C         | -0.25                   | +0.25 | nA   |    |
|   |                         |  |                                     | 2, 3  | +125°C, -55°C | -20                     | +20   | nA   |    |
|   |                         |  | $V_{IN} = 0.8V$ or<br>2.4V (Note 1) | 1   | +25°C         | -0.25                   | +0.25 | nA   |    |
|   |                         |  |                                     | 2, 3  | +125°C, -55°C | -20                     | +20   | nA   |    |
|   |                         | $V_+ = 16.5V$ ,<br>$V_- = -16.5V$ ,<br>$V_D = 15.5V$ ,<br>$V_S = -15.5V$ | $V_{IN} = 2.4V$                     | 1   | +25°C         | -0.25                   | +0.25 | nA   |    |
|   |                         |  |                                     | 2, 3  | +125°C, -55°C | -20                     | +20   | nA   |    |
|   |                         |  | $V_{IN} = 0.8V$                     | 1   | +25°C         | -0.25                   | +0.25 | nA   |    |
|   |                         |  |                                     | 2, 3  | +125°C, -55°C | -20                     | +20   | nA   |    |
|   |                         |  | $V_{IN} = 0.8V$ or<br>2.4V (Note 1) | 1   | +25°C         | -0.25                   | +0.25 | nA   |    |
|   |                         |  |                                     | 2, 3  | +125°C, -55°C | -20                     | +20   | nA   |    |
| Channel ON Leakage Current<br>DG411/883<br>DG412/883<br>DG413/883                                       | $I_{D(ON)} + I_{S(ON)}$ | $V_+ = 16.5V$ ,<br>$V_- = -16.5V$ ,<br>$V_S = V_D = \pm 15.5V$           | $V_{IN} = 0.8V$                     | 1   | +25°C         | -0.4                    | +0.4  | nA   |    |
|   |                         |  |                                     | 2, 3  | +125°C, -55°C | -40                     | +40   | nA   |    |
|   |                         |  | $V_{IN} = 2.4V$                     | 1   | +25°C         | -0.4                    | +0.4  | nA   |    |
|   |                         |  |                                     | 2, 3  | +125°C, -55°C | -40                     | +40   | nA   |    |
|   |                         |  | $V_{IN} = 0.8V$ or<br>2.4V (Note 1) | 1   | +25°C         | -0.4                    | +0.4  | nA   |    |
|   |                         |  |                                     | 2, 3  | +125°C, -55°C | -40                     | +40   | nA   |    |
|   |                         | Input Current with $V_{IN}$ Low  | $I_{IL}$                            | Input Under Test = 0.8V,<br>All Others = 2.4V             | 1, 2, 3       | +25°C, +125°C,<br>-55°C | -0.5  | +0.5 | μA |
|   |                         | Input Current with $V_{IN}$ High   | $I_{IH}$                            | Input Under Test = 2.4V,<br>All Others = 0.8V             | 1, 2, 3       | +25°C, +125°C,<br>-55°C | -0.5  | +0.5 | μA |
|   |                         | Positive Supply Current  | I+                                  | $V_+ = 16.5V$ , $V_- = -16.5V$ ,<br>$V_{IN} = 0V$ or 5.0V | 1             | +25°C                   | -     | +1.0 | μA |
| 2, 3  | +125°C, -55°C           |  |                                     |   | -             | +5.0                    | μA    |      |    |
| $V_+ = 13.2V$ , $V_- = 0V$ ,<br>$V_{IN} = 0V$ or 5.0V<br>$V_L = 5.25V$                                  | 1                       |  |                                     | +25°C   | -             | +1.0                    | μA    |      |    |
|   | 2, 3                    |  |                                     | +125°C, -55°C   | -             | +5.0                    | μA    |      |    |
| Negative Supply Current   | I-                      | $V_+ = 16.5V$ , $V_- = -16.5V$ ,<br>$V_{IN} = 0V$ or 5.0V                | 1                                   | +25°C   | -1.0          | -                       | μA    |      |    |
|   |                         |  | 2, 3                                | +125°C, -55°C   | -5.0          | -                       | μA    |      |    |
|   |                         | $V_+ = 13.2V$ , $V_- = 0V$ ,<br>$V_{IN} = 0V$ or 5.0V<br>$V_L = 5.25V$   | 1                                   | +25°C   | -1.0          | -                       | μA    |      |    |
|   |                         |  | 2, 3                                | +125°C, -55°C   | -5.0          | -                       | μA    |      |    |
| Logic Supply Current  | $I_L$                   | $V_+ = 16.5V$ , $V_- = -16.5V$ ,<br>$V_{IN} = 0V$ or 5.0V                | 1                                   | +25°C   | -             | +1.0                    | μA    |      |    |
|   |                         |  | 2, 3                                | +125°C, -55°C   | -             | +5.0                    | μA    |      |    |
|   |                         | $V_+ = 13.2V$ , $V_- = 0V$ ,<br>$V_{IN} = 0V$ or 5.0V<br>$V_L = 5.25V$   | 1                                   | +25°C   | -             | +1.0                    | μA    |      |    |
|   |                         |  | 2, 3                                | +125°C, -55°C   | -             | +5.0                    | μA    |      |    |
| Ground Current  | $I_{GND}$               | $V_+ = 16.5V$ , $V_- = -16.5V$ ,<br>$V_{IN} = 0V$ or 5.0V                | 1                                   | +25°C   | -1.0          | -                       | μA    |      |    |
|   |                         |  | 2, 3                                | +125°C, -55°C   | -5.0          | -                       | μA    |      |    |
|   |                         | $V_+ = 13.2V$ , $V_- = 0V$ ,<br>$V_{IN} = 0V$ or 5.0V<br>$V_L = 5.25V$   | 1                                   | +25°C   | -1.0          | -                       | μA    |      |    |
|   |                         |  | 2, 3                                | +125°C, -55°C   | -5.0          | -                       | μA    |      |    |

## Specifications DG411/883, DG412/883, DG413/883

**TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS**

Device Tested at:  $V_+ = +15V$ ,  $V_- = -15V$ ,  $V_L = 5V$ ,  $GND = 0V$ , Unless Otherwise Specified

| PARAMETERS    | SYMBOL    | CONDITIONS  | GROUP A SUBGROUP | TEMPERATURE  | LIMITS |     | UNITS |
|---------------|-----------|---|------------------|--------------|--------|-----|-------|
|               |           |   |                  |              | MIN    | MAX |       |
| Turn ON Time  | $t_{ON}$  | $C_L = 35pF$ , $V_S = \pm 10V$ ,<br>$R_L = 300\Omega$                           | 9, 11            | +25°C, -55°C | 0      | 175 | ns    |
|               |           |   | 10               | +125°C       | 0      | 240 | ns    |
|               |           | $V_+ = 12V$ , $V_- = 0V$ ,<br>$C_L = 35pF$ , $V_S = +8V$ ,<br>$R_L = 300\Omega$ | 9, 11            | +25°C, -55°C | 0      | 250 | ns    |
|               |           |   | 10               | +125°C       | 0      | 400 | ns    |
| Turn OFF Time | $t_{OFF}$ | $C_L = 35pF$ , $V_S = \pm 10V$ ,<br>$R_L = 300\Omega$                           | 9, 11            | +25°C, -55°C | 0      | 145 | ns    |
|               |           |   | 10               | +125°C       | 0      | 160 | ns    |
|               |           | $V_+ = 12V$ , $V_- = 0V$ ,<br>$C_L = 35pF$ , $V_S = +8V$ ,<br>$R_L = 300\Omega$ | 9, 11            | +25°C, -55°C | 0      | 125 | ns    |
|               |           |   | 10               | +125°C       | 0      | 140 | ns    |

**TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS (NOTE 1)**

Device Tested at:  $V_+ = +15V$ ,  $V_- = -15V$ ,  $V_L = 5V$ ,  $GND = 0V$ , Unless Otherwise Specified

| PARAMETERS       | SYMBOL | CONDITIONS   | GROUP A SUBGROUP | TEMPERATURE | LIMITS |      | UNITS |
|------------------|--------|--|------------------|-------------|--------|------|-------|
|                  |        |  |                  |             | MIN    | MAX  |       |
| Charge Injection | Q      | See Figure 2, $V_G = 0V$ , $R_G = 0\Omega$ ,<br>$T_A = +25^\circ C$ , $C_L = 10nF$                             | 9                | +25°C       | -100   | +100 | pC    |
|                  |        |  |                  | +25°C       |        |      | pC    |
|                  |        | See Figure 2,<br>$V_G = 6V$ , $R_G = 0\Omega$ , $T_A = +25^\circ C$<br>$C_L = 10nF$ , $V_+ = 12V$ , $V_- = 0V$ | 9                | +25°C       | -100   | +100 | pC    |
|                  |        |  |                  | +25°C       |        |      | pC    |

**NOTES:**

- $V_{IN}$  = Input Voltage to Perform Proper Function.
- Signals on  $S_X$ ,  $D_X$  or  $IN_X$  exceeding  $V_+$  or  $V_-$  will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads soldered or welded to PC board.
- Parameters listed in Table 3 are controlled via design or process and are not directly tested at final production. These parameters are lab characterized upon initial design release or upon design changes. These parameters are guaranteed by characterization based upon data from multiple production runs which reflect lot to lot and within lot variation.

**TABLE 4. ELECTRICAL TEST REQUIREMENTS**

| MIL-STD-883 TEST REQUIREMENTS               | SUBGROUPS (SEE TABLES 1 AND 2) |
|---|--------------------------------|
| Interim Electrical Parameters (Pre Burn-In) | 1                              |
| Final Electrical Test Parameters            | 1 (Note 1), 2, 3, 9, 10, 11    |
| Group A Test Requirements                   | 1, 2, 3, 9, 10, 11             |
| Groups C and D Endpoints                    | 1                              |

**NOTE:**

- PDA applies to Subgroup 1 only.

## DG411/883, DG412/883, DG413/883

### Die Characteristics

#### DIE DIMENSIONS:

2760 $\mu\text{m}$  x 1780 $\mu\text{m}$  x 485  $\pm$  25 $\mu\text{m}$

#### METALLIZATION:

Type: SiAl

Thickness: 12k $\text{\AA}$   $\pm$  1k $\text{\AA}$

#### GLASSIVATION:

Type: Nitride

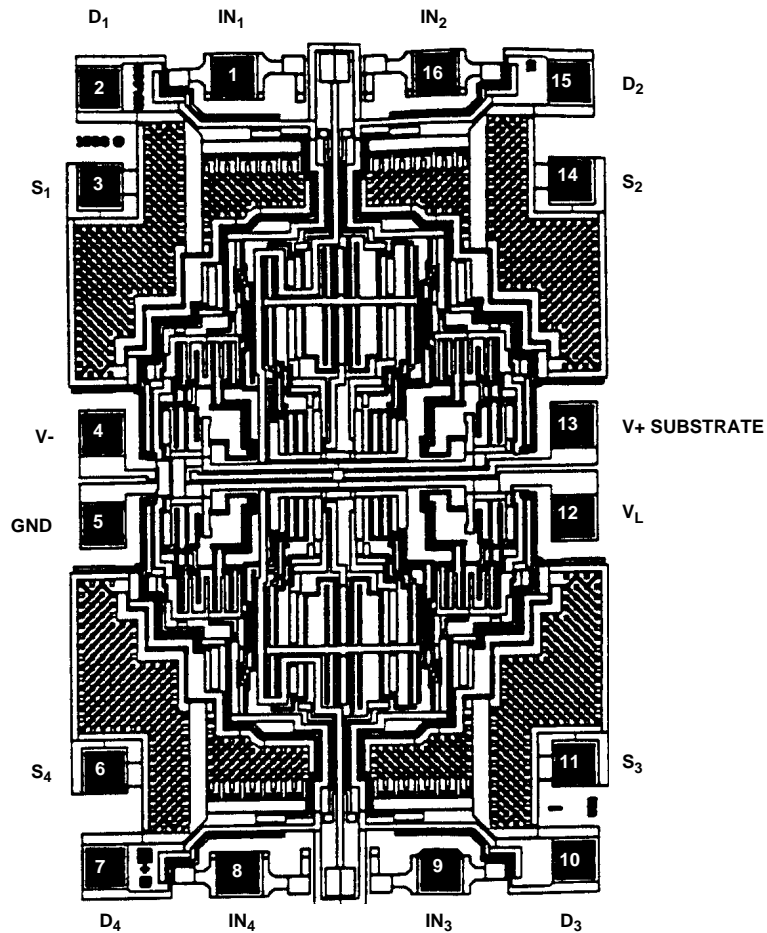
Thickness: 8k $\text{\AA}$   $\pm$  1k $\text{\AA}$

#### WORST CASE CURRENT DENSITY:

1.5 x 10<sup>5</sup>A/cm<sup>2</sup>

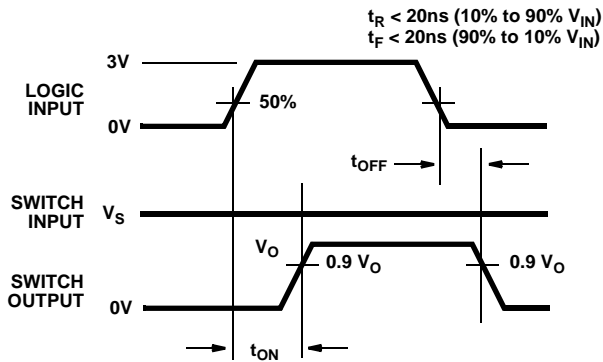
### Metallization Mask Layout

DG411/883, DG412/883, DG413/883



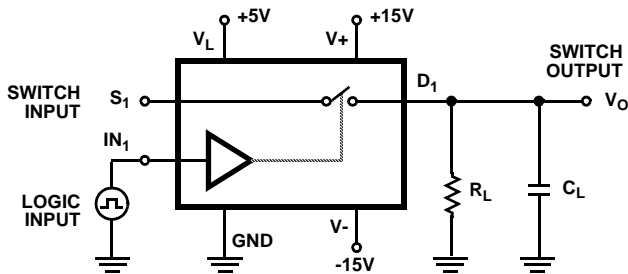
**Test Circuits**

$V_O$  is the steady state output with the switch on. Feedthrough via switch capacitance may result in spikes at the leading and trailing edge of the output waveform.



NOTE: Logic input waveform is inverted for switches that have the opposite logic sense.

FIGURE 1A.



Repeat test for all IN and S.  
For load conditions, see Specifications  $C_L$  (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + R_{DS(ON)}}$$

FIGURE 1B.

FIGURE 1. SWITCHING TIME

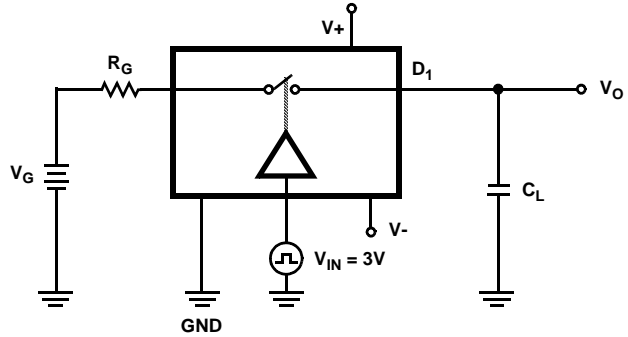
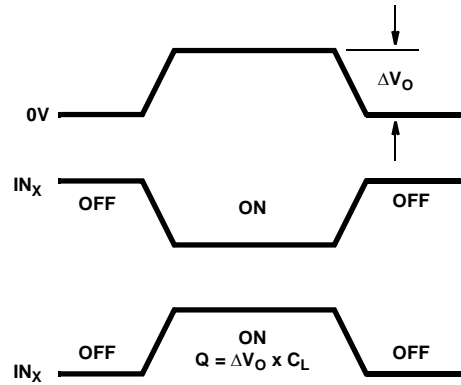


FIGURE 2A.



$IN_x$  dependent on switch configuration input polarity determined by sense of switch.

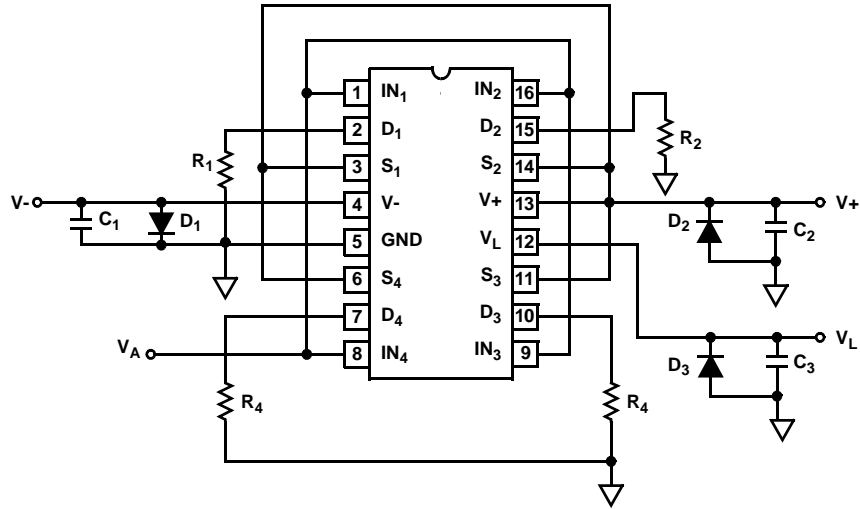
FIGURE 2B.

FIGURE 2. CHARGE INJECTION

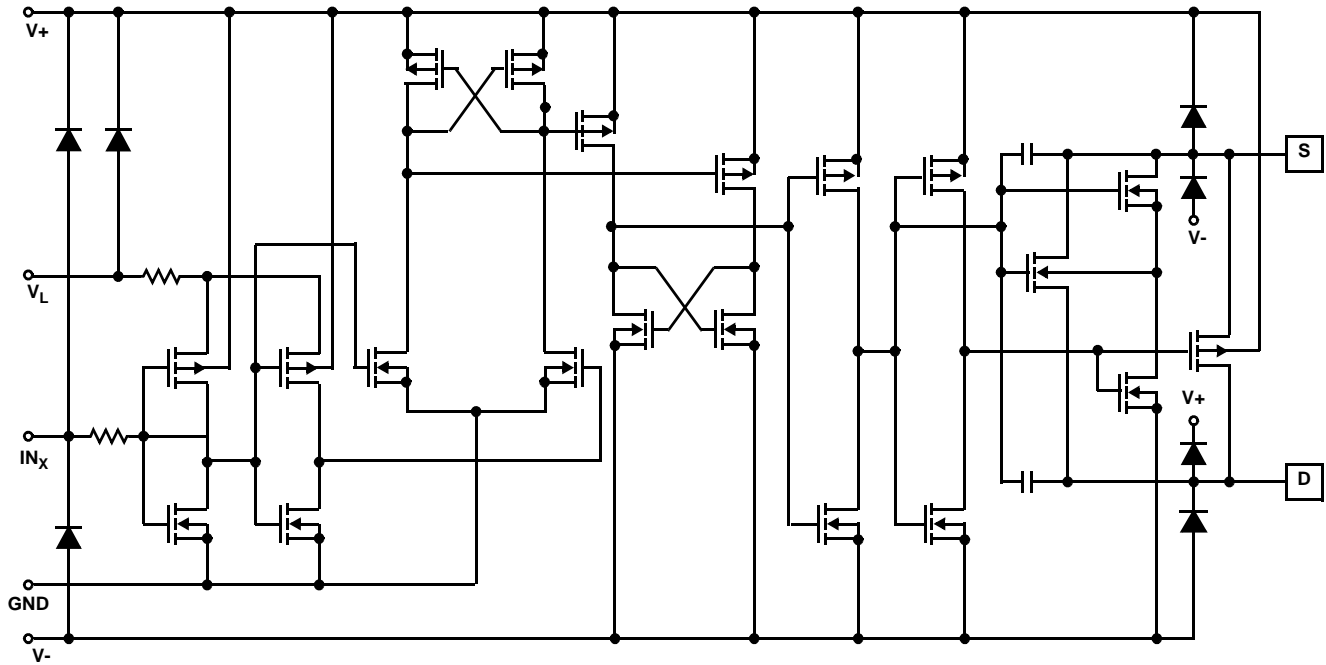
DG411/883, DG412/883, DG413/883

**Burn-In Circuit**

DG411/883, DG412/883, DG413/883 CERAMIC DIP



**Typical Schematic Diagram (Typical Channel)**

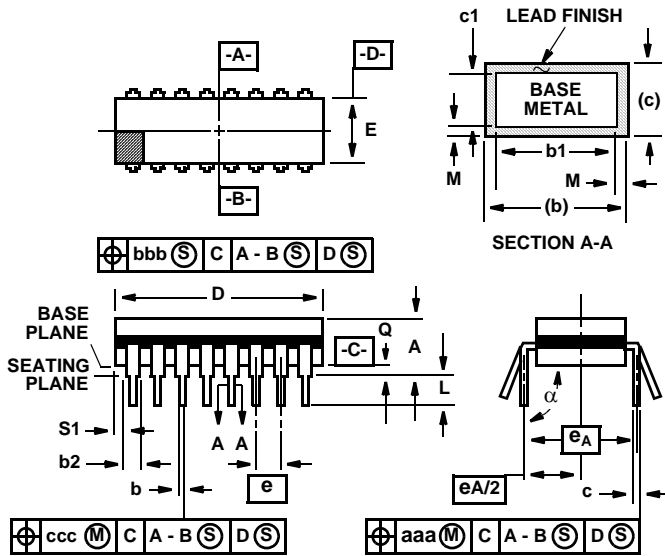




DG411/883, DG412/883, DG413/883

Ceramic Dual-In-Line Frit Seal Packages (CerDIP)

F16.3 MIL-STD-1835 GDIP1-T16 (D-2, CONFIGURATION A)  
16 LEAD CERAMIC DUAL-IN-LINE FRIT SEAL PACKAGE



| SYMBOL   | INCHES    |        | MILLIMETERS |       | NOTES |
|----------|-----------|--------|-------------|-------|-------|
|          | MIN       | MAX    | MIN         | MAX   |       |
| A        | -         | 0.200  | -           | 5.08  | -     |
| b        | 0.014     | 0.026  | 0.36        | 0.66  | 2     |
| b1       | 0.014     | 0.023  | 0.36        | 0.58  | 3     |
| b2       | 0.045     | 0.065  | 1.14        | 1.65  | -     |
| b3       | 0.023     | 0.045  | 0.58        | 1.14  | 4     |
| c        | 0.008     | 0.018  | 0.20        | 0.46  | 2     |
| c1       | 0.008     | 0.015  | 0.20        | 0.38  | 3     |
| D        | -         | 0.840  | -           | 21.34 | 5     |
| E        | 0.220     | 0.310  | 5.59        | 7.87  | 5     |
| e        | 0.100 BSC |        | 2.54 BSC    |       | -     |
| eA       | 0.300 BSC |        | 7.62 BSC    |       | -     |
| eA/2     | 0.150 BSC |        | 3.81 BSC    |       | -     |
| L        | 0.125     | 0.200  | 3.18        | 5.08  | -     |
| Q        | 0.015     | 0.060  | 0.38        | 1.52  | 6     |
| S1       | 0.005     | -      | 0.13        | -     | 7     |
| $\alpha$ | 90°       | 105°   | 90°         | 105°  | -     |
| aaa      | -         | 0.015  | -           | 0.38  | -     |
| bbb      | -         | 0.030  | -           | 0.76  | -     |
| ccc      | -         | 0.010  | -           | 0.25  | -     |
| M        | -         | 0.0015 | -           | 0.038 | 2, 3  |
| N        | 16        |        | 16          |       | 8     |

NOTES:

1. Index area: A notch or a pin one identification mark shall be located adjacent to pin one and shall be located within the shaded area shown. The manufacturer's identification shall not be used as a pin one identification mark.
2. The maximum limits of lead dimensions b and c or M shall be measured at the centroid of the finished lead surfaces, when solder dip or tin plate lead finish is applied.
3. Dimensions b1 and c1 apply to lead base metal only. Dimension M applies to lead plating and finish thickness.
4. Corner leads (1, N, N/2, and N/2+1) may be configured with a partial lead paddle. For this configuration dimension b3 replaces dimension b2.
5. This dimension allows for off-center lid, meniscus, and glass overrun.
6. Dimension Q shall be measured from the seating plane to the base plane.
7. Measure dimension S1 at all four corners.
8. N is the maximum number of terminal positions.
9. Dimensioning and tolerancing per ANSI Y14.5M - 1982.
10. Controlling dimension: INCH.

Rev. 0 4/94

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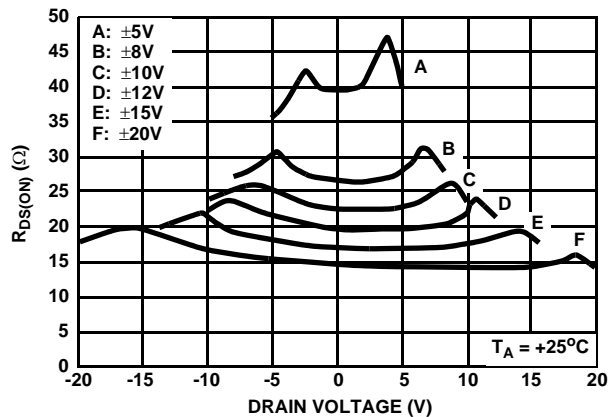
## DESIGN INFORMATION

### Monolithic Quad SPST CMOS Analog Switches

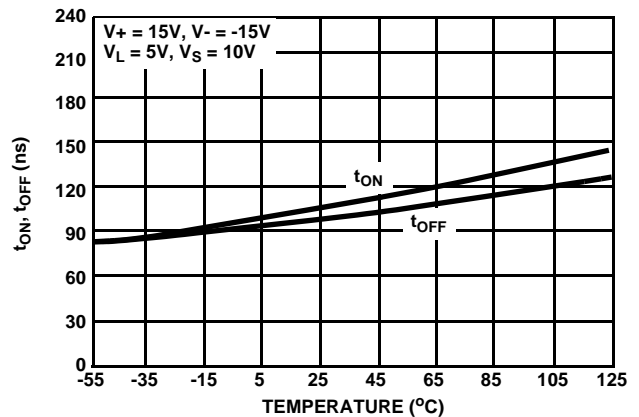
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#### Typical Performance Curves

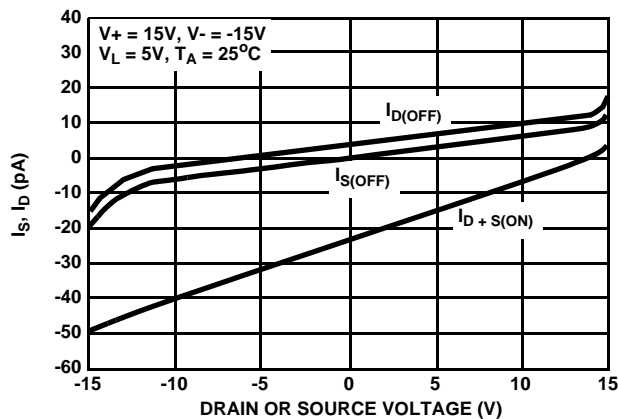
ON-RESISTANCE vs  $V_D$  AND POWER SUPPLY VOLTAGE



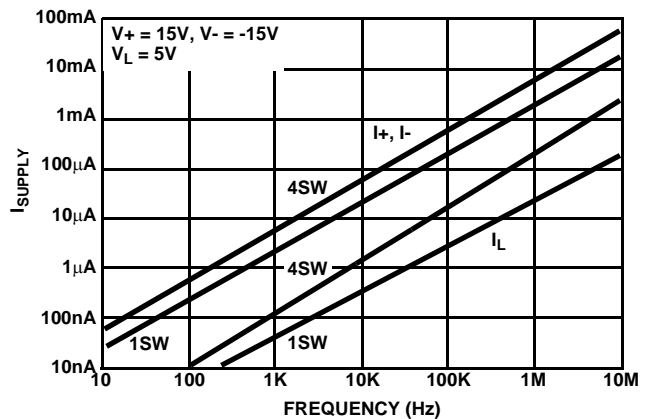
SWITCHING TIME vs TEMPERATURE



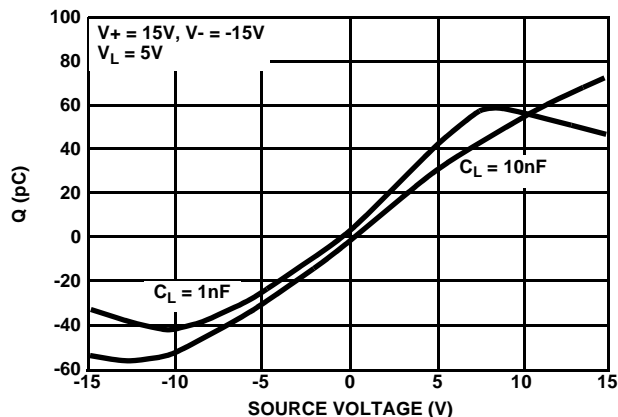
LEAKAGE CURRENT vs ANALOG VOLTAGE



SUPPLY CURRENT vs INPUT SWITCHING FREQUENCY



CHARGE INJECTION vs ANALOG VOLTAGE ( $V_D$ )



CHARGE INJECTION vs ANALOG VOLTAGE ( $V_S$ )

